100V N-Ch Power MOSFET

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V_{DS}		100	V
$R_{DS(on),typ}$	V_{GS}=10V	8.3	m
$R_{DS(on),typ}$	V_{GS}=4.5V	10.8	m
$I_{D\ (Sillicon\ Limited)}$		67	A

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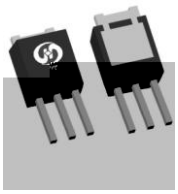

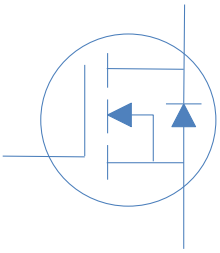

Part Number	Package	Marking
HGD098N10SL	TO-252	GD098N10SL
HGI098N10SL	TO-251	GI098N10SL

Absolute Maximum Ratings at T_j=25℃ (unless otherwise specified)

Parameter	Symbol	Conditions	Value	Unit
Continuous Drain Current (Silicon Limited)	I_D	T_C=25℃	67	A
		T_C=100℃	47	
Drain to Source Voltage	V_{DS}	-	100	V
Gate to Source Voltage	V_{GS}	-	±20	V
Pulsed Drain Current	I_{DM}	-	160	A
Avalanche Energy, Single Pulse	E_{AS}	L=0.1mH, T_C=25℃	31	mJ
Power Dissipation	P_D	T_C=25℃	94	W
Operating and Storage Temperature	T_J, T_{stg}	-	-55 to175	℃

Absolute Maximum Ratings

Parameter	Symbol	Max	Unit
Thermal Resistance Junction-Ambient	R_{JA}	50	℃/W
Thermal Resistance Junction-Case	R_{JC}	1.6	℃/W

					-
					-
Turn on Delay Time	$t_{d(on)}$		-	13	-
		V_{DD}=50V, I_D=20A, V_{GS}=10V,		6	-
		R_G=10 ,		24	-
Fall Time	t_f		-	5	

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Fig 1. Typical Output Characteristics

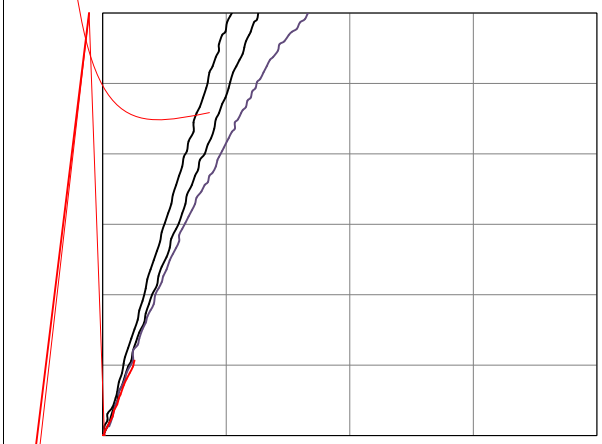


Figure 2. On-Resistance vs. Gate-Source Voltage

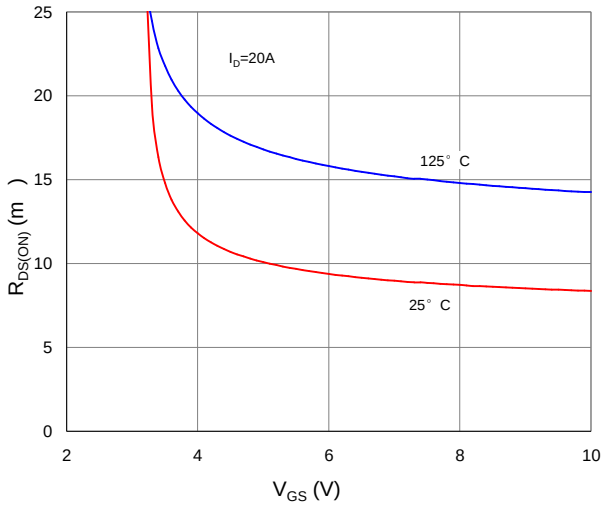


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

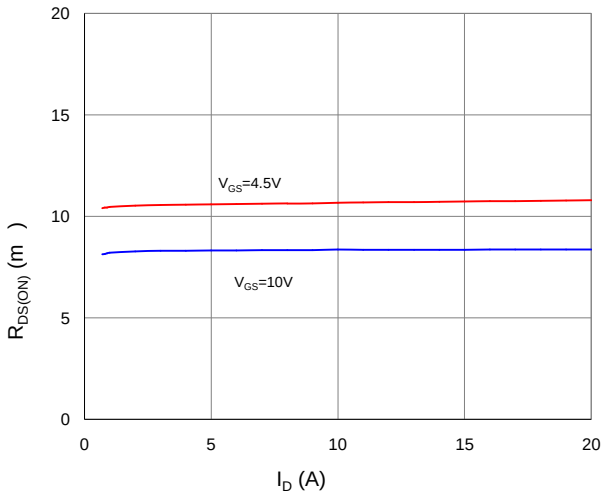


Figure 4. Normalized On-Resistance vs. Junction Temperature

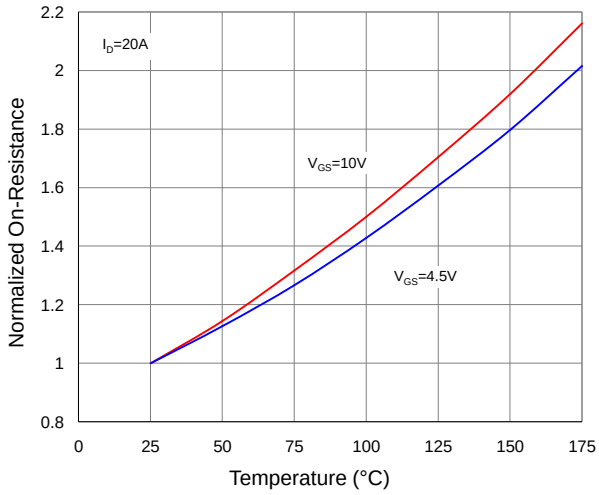


Figure 5. Typical Transfer Characteristics

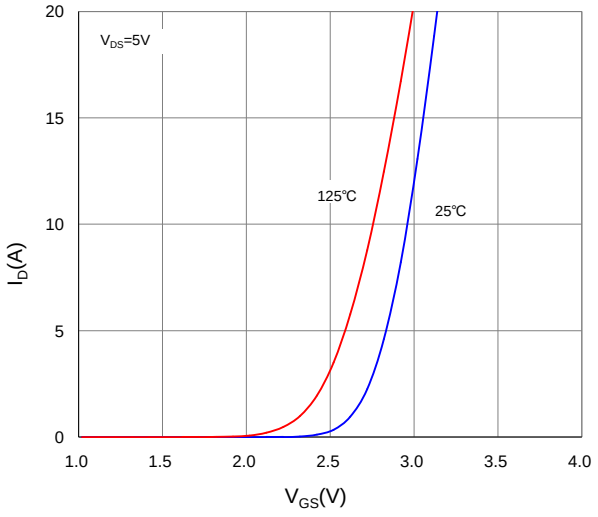
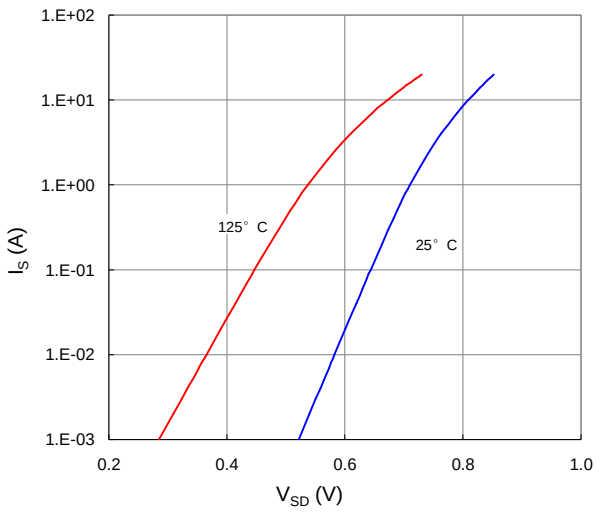


Figure 6. Typical Source-Drain Diode Forward Voltage



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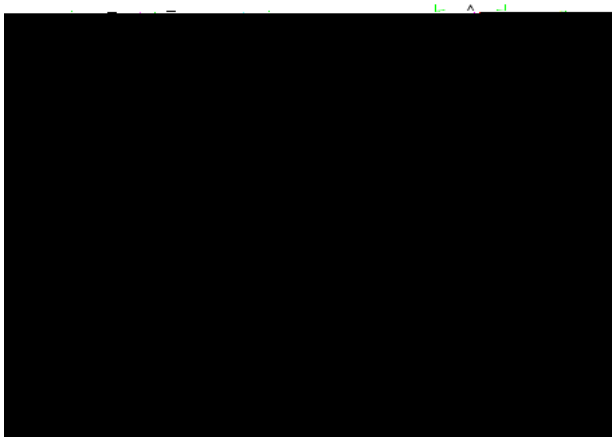
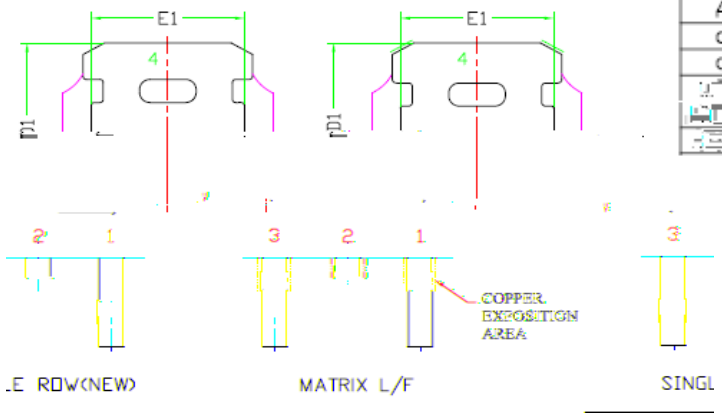
Package Outline

TO-252, 2 leads

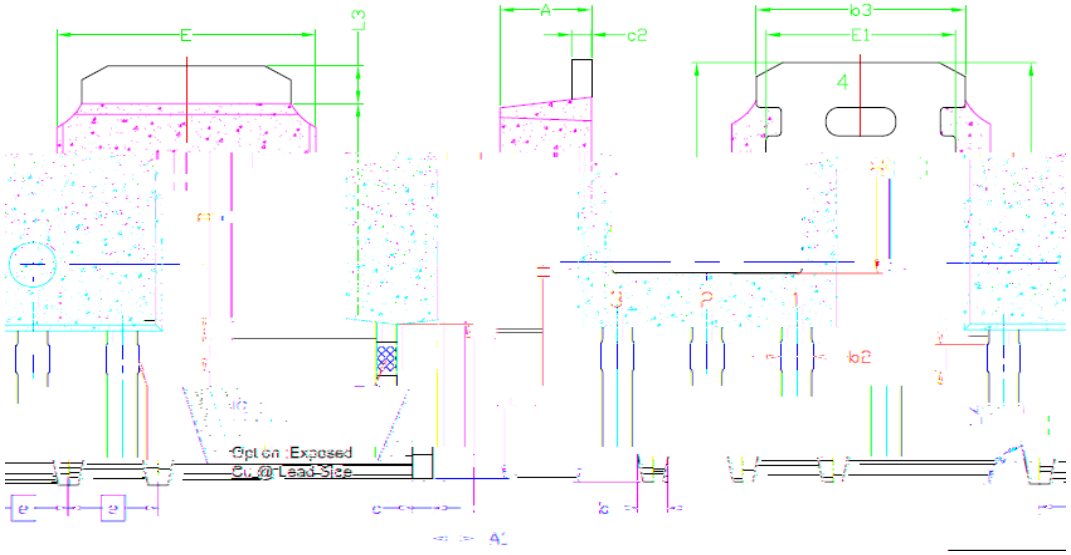


SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1		2.743 REF	
L2		0.508 BSC	
L3	0.89	--	1.27
L4	0.64	--	1.01
L5	--	--	--
D	6.00	6.10	6.223
H	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
e		2.286 BSC	
A	2.20	2.30	2.38
A1	0	--	0.127
c	0.46	0.50	0.60
c2	0.46	0.50	0.58



Package Outline

TO-251, 3 leads



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
E	6.40	6.60	6.731
L	3.98	4.13	4.28
L3	0.89	--	1.27
L4		0.698 REF	
L5	0.972	1.099	1.226
D	6.00	6.10	6.223
H	11.05	11.25	11.45
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
e		2.286 BSC	
A	2.20	2.30	2.38
A1	0.89	1.04	1.15
c	0.46	0.50	0.60
c2	0.46	0.50	0.60
D1	5.10	--	--
E1	4.40	--	--
α		79° REF	